

POWER PIN DIODES

DESCRIPTION

These series of PIN diodes are designed for applications requiring small package size and moderate average power handling capability. The low capacitance of the UM6000 and UM6600 allows them to be used as series switching elements to 1 GHz. The low resistance of the UM6200 is useful in applications where forward bias current must be minimized.

Because of its thick I-region width and long lifetime the UM6000 and UM6600 have been used in distortion sensitive and high peak power applications, including receiver protectors, TACN, and IFF equipment. Their low capacitance allows them to be useful as attenuator diodes at frequencies greater than 1 GHz. The UM6200 has been

used successfully in switches in which low insertion loss at low bias current is required. The "A" style package for this series is the smallest Microsemi PIN diode package. It has been used successfully in many microwave applications using coaxial, microstrip, and stripline techniques at frequencies beyond X-Band. The "B" and "E" style leaded packages offer the highest available power dissipation for a package this small. They have been used extensively as series switch elements in microstrip circuits. The "C" style package duplicates the physical outline available in conventional ceramic-metal packages but incorporates the many reliability advantages of the Microsemi construction.

KEY FEATURES

- Voltage ratings to 1000V
- Average power dissipation to 6 W
- Series resistance as low as 0.4 Ω
- Carrier lifetime greater than 1.0 µs
- Non cavity design
- Thermally matched configuration
- Low capacitance at 0 V bias
- Low conductance at 0 V bias
- Compatible with automatic insertion equipment

IMPORTANT: For the most current data, consult *MICROSEMI*'s website: http://www.microsemi.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED) **Package** Condition UM6000/UM6600 **UM6200** PD PD θ 25 °C Pin Temperature 25 °C/W A & C 6 W 4 W 37.5 °C/W **B & E** ½ in. total length to 25 °C Contact 60 °C/W 2.0 W 75 °C/W 2.5 W 0.5 W 0.5 W 25 °C End Cap Temperature 27.5°C/W SM 4.5 W 3.0 W 42.5 °C/W UM6000 25 kW ΑII 1 us pulse (Single) 10 kW UM6600 13 kW

UM6201	UM6601
LIMACOOO	
UM6202	UM6602
UM6204	-
-	UM6606
-	UM6610
	-

APPLICATIONS/BENEFITS

- Isolated stud package available
- Surface mount package available
- RoHS compliant packaging available: use UMX6001B, etc.

UM6000/UM62000/UM660

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ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)								
Parameter	Symbol	Conditions	UM6600	UM6000	UM6200	Units		
Reverse Current (Max)	I_{R}	At rated voltage	10	10	10	uA		
Series Resistance(Max)	Rs	If = 100 mA, F= 100 MHz	2.5	1.7	0.4	Ohms		
Capacitance (Max)	Ст	V _R = 100 V, F = 1 MH _Z	0.4	0.5	1.1	pF		
Parallel Resistance(Min) Rp	$V_R = 100 \text{ V}, F = 100 \text{ MHz}$	300k	300k	350k	Ohms		
Carrier Lifetime(Min)	τ	I _F = 10 mA	1.0	1.0	0.6	us		
I-Region Width (Min)	W	-	150	150	40	um		

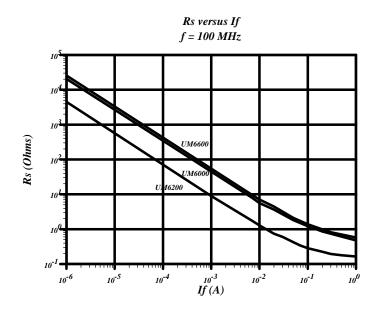




Style "B"

Style "SM"

UM6000/UM6200/UM6600



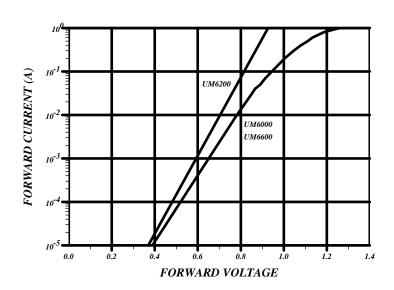
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POWER PIN DIODES

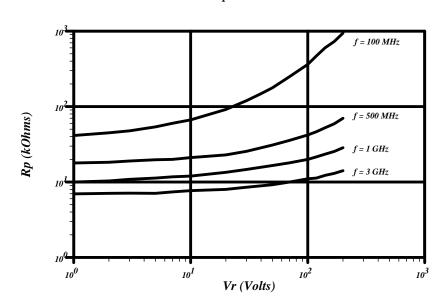
UM6000/UM6200/UM6600

FORWARD VOLTAGE versus CURRENT



UM6000/UM6600

Rp versus Vr

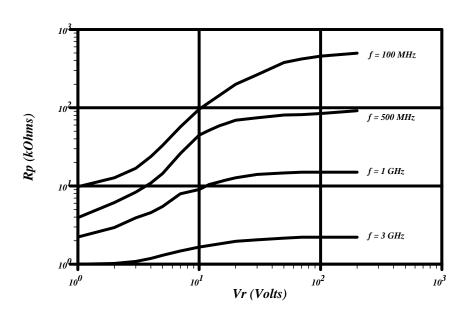




POWER PIN DIODES

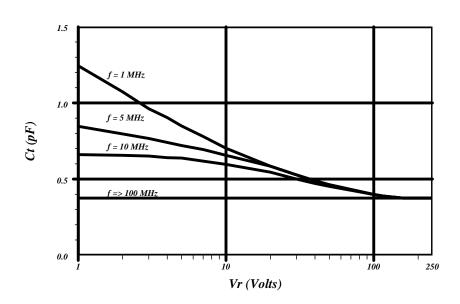
UM6200

Rp versus Vr



UM6000

Ct versus Vr

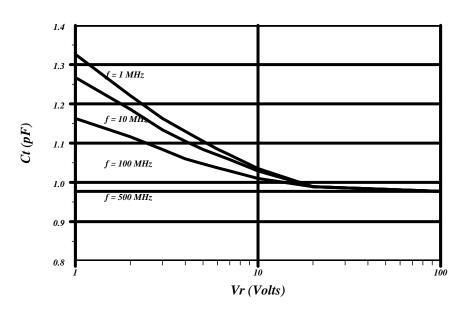




POWER PIN DIODES

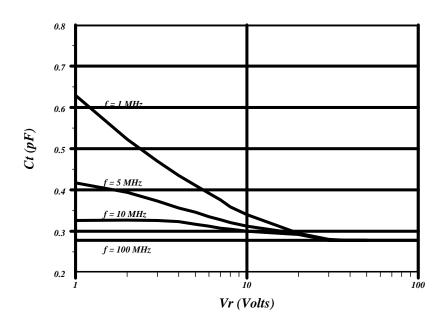
UM6200

Ct versus Vr



UM6600

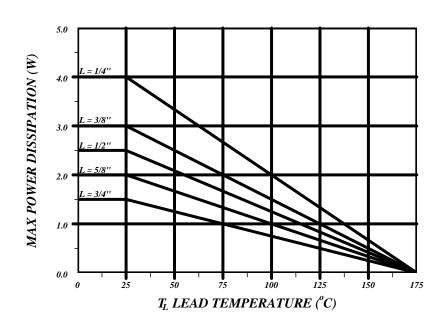
Ct versus Vr



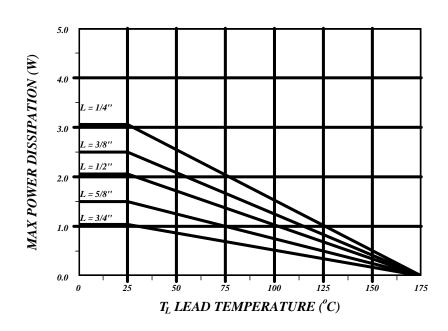


POWER PIN DIODES

UM6000/UM6200 MAX POWER DISSIPATION versus LEAD TEMPERATURE



UM6600 MAX POWER DISSIPATION versus LEAD TEMPERATURE

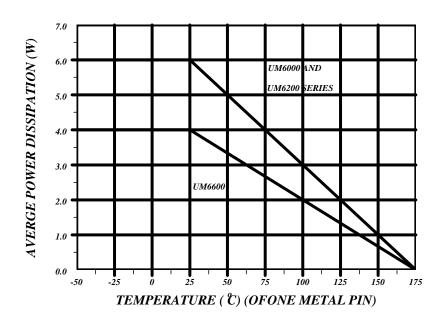




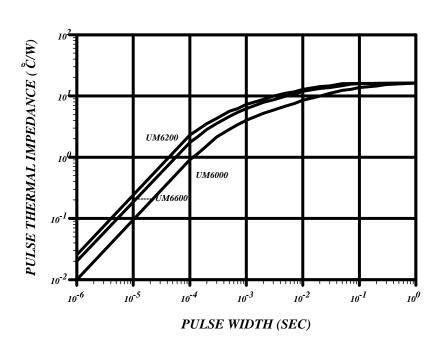
POWER PIN DIODES

UM6000/UM6200/UM6600

AVERGE POWER DISSIPATION versus TEMPERATURE



UM6000/UM6200/UM6600 PULSE THERMAL IMPEDANCE VS PULSE WIDTH

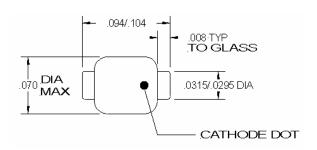


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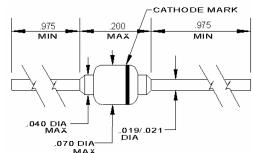


POWER PIN DIODES

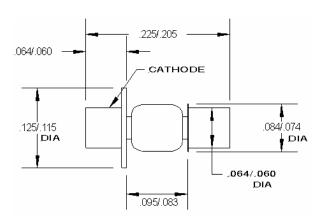
STYLE "A"



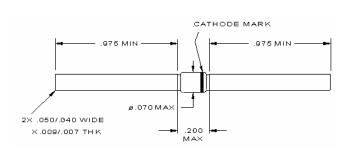
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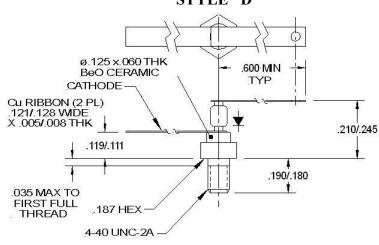
STYLE "C"



STYLE "E"

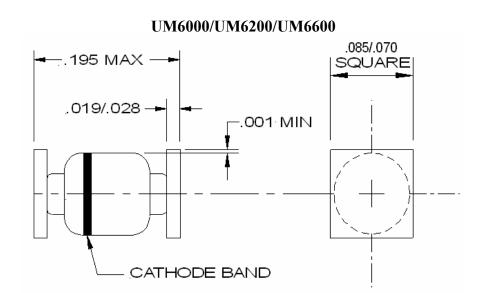


STYLE "D"

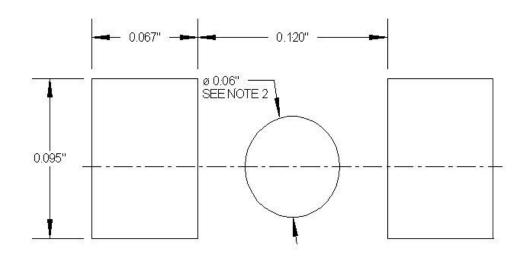




POWER PIN DIODES



UM6000/UM6200/UM6600 STYLE "SM" FOOTPRINT





POWER PIN DIODES

NOTES:

- 1. These dimensions will match the terminals and provide for additional solder fillets at the outboard ends at least as wide as the terminals themselves, assuming accuracy of placement within 0.005"
- 2. If the mounting method chosen requires use of an adhesive separate from the solder compound, a round (or square) spot of cement as shown should be centrally located.

NOTES:

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